## NSN 5962-01-358-9694

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## **Body Length:** 1.490 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** 0.217 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Burn in and monolithic and programmed and erasable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic Input Circuit Pattern: 21 input **Case Outline Source And Designator:** D-10 mil-m-38510 **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -0.3 volts power source and 6.25 volts power source **Time Rating Per Chacteristic:** 200.00 nanoseconds access Memory Device Type: Eeprom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 28 printed circuit Shelf Life: N/a Unit Of Measure: **Demilitarization:**

Yes - demil/mli

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